

## Semiconductor Memory with Wordline Timing

### Abstract of the Disclosure

5 A semiconductor memory with wordline timing, which links activating a wordline to an isolation signal. The isolation signal is applied to a memory section adjacent the memory section containing the wordline to be activated. Upon such an isolation signal shifting low and isolating the adjacent memory section, a timing circuit triggers a wordline decoder to activate a select wordline. The timing circuit prevents activation of the wordline decoder until the isolation signal is received.

"Express Mail" mailing label number: EL671641471US

Date of Deposit: June 14, 2001

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T04T90 24T8860